

N-Channel Power MOSFET

60V, 27A, 25mΩ

FEATURES

- Low $R_{DS(on)}$ to minimize conductive losses
- Logic level
- Low gate charge for fast power switching
- 100% UIS and R_g Tested
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

KEY PERFORMANCE PARAMETERS

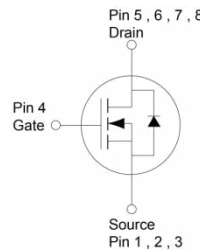
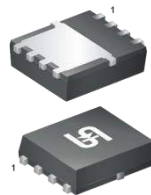
| PARAMETER | VALUE | UNIT |
|--------------------|-----------------|------|
| V_{DS} | 60 | V |
| $R_{DS(on)}$ (max) | $V_{GS} = 10V$ | 25 |
| | $V_{GS} = 4.5V$ | 28 |
| Q_g | 11 | nC |

APPLICATIONS

- BLDC Motor Control
- Battery Power Management
- DC-DC Converter
- Secondary Synchronous Rectification



PDFN33



Note: MSL 1 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

| PARAMETER | SYMBOL | LIMIT | UNIT |
|--|----------------|---------------------------|------------------|
| Drain-Source Voltage | V_{DS} | 60 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | V |
| Continuous Drain Current (Note 1) | I_D | $T_C = 25^\circ\text{C}$ | 27 |
| | | $T_A = 25^\circ\text{C}$ | 6 |
| Pulsed Drain Current | I_{DM} | 108 | A |
| Single Pulse Avalanche Current (Note 2) | I_{AS} | 13 | A |
| Single Pulse Avalanche Energy (Note 2) | E_{AS} | 25 | mJ |
| Total Power Dissipation | P_D | $T_C = 25^\circ\text{C}$ | 42 |
| | | $T_C = 125^\circ\text{C}$ | 8 |
| Total Power Dissipation | P_D | $T_A = 25^\circ\text{C}$ | 1.9 |
| | | $T_A = 125^\circ\text{C}$ | 0.4 |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | - 55 to +150 | $^\circ\text{C}$ |

THERMAL PERFORMANCE

| PARAMETER | SYMBOL | MAXIMUM | UNIT |
|--|-----------------|---------|---------------------------|
| Junction to Case Thermal Resistance | $R_{\theta JC}$ | 3 | $^\circ\text{C}/\text{W}$ |
| Junction to Ambient Thermal Resistance | $R_{\theta JA}$ | 65 | $^\circ\text{C}/\text{W}$ |

Thermal Performance Note: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design. The $R_{\theta JA}$ limit presented here is based on mounting on a 1 in² pad of 2 oz copper.

| ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted) | | | | | | |
|---|---|--------------|-----|------|-----------|---------------|
| PARAMETER | CONDITIONS | SYMBOL | MIN | TYP | MAX | UNIT |
| Static | | | | | | |
| Drain-Source Breakdown Voltage | $V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$ | BV_{DSS} | 60 | -- | -- | V |
| Gate Threshold Voltage | $V_{GS} = V_{DS}, I_D = 250\mu\text{A}$ | $V_{GS(TH)}$ | 1 | 1.8 | 2.5 | V |
| Gate-Source Leakage Current | $V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$ | I_{GSS} | -- | -- | ± 100 | nA |
| Drain-Source Leakage Current | $V_{GS} = 0\text{V}, V_{DS} = 60\text{V}$ | I_{DSS} | -- | -- | 1 | μA |
| | $V_{GS} = 0\text{V}, V_{DS} = 60\text{V}$ $T_J = 125^\circ\text{C}$ | | -- | -- | 100 | |
| Drain-Source On-State Resistance (Note 3) | $V_{GS} = 10\text{V}, I_D = 6\text{A}$ | $R_{DS(on)}$ | -- | 18 | 25 | m Ω |
| | $V_{GS} = 4.5\text{V}, I_D = 5\text{A}$ | | -- | 22 | 28 | |
| Forward Transconductance (Note 3) | $V_{DS} = 10\text{V}, I_D = 6\text{A}$ | g_{fs} | -- | 23 | -- | S |
| Dynamic (Note 4) | | | | | | |
| Total Gate Charge | $V_{GS} = 10\text{V}, V_{DS} = 30\text{V},$ $I_D = 6\text{A}$ | Q_g | -- | 23 | -- | nC |
| Total Gate Charge | $V_{GS} = 4.5\text{V}, V_{DS} = 30\text{V},$ $I_D = 5\text{A}$ | Q_g | -- | 11 | -- | |
| Gate-Source Charge | | Q_{gs} | -- | 4 | -- | |
| Gate-Drain Charge | | Q_{gd} | -- | 5 | -- | |
| Input Capacitance | $V_{GS} = 0\text{V}, V_{DS} = 30\text{V},$ $f = 1.0\text{MHz}$ | C_{iss} | -- | 1307 | -- | pF |
| Output Capacitance | | C_{oss} | -- | 86 | -- | |
| Reverse Transfer Capacitance | | C_{rss} | -- | 27 | -- | |
| Gate Resistance | $f = 1.0\text{MHz}$ | R_g | 0.6 | 2 | 4 | Ω |
| Switching (Note 4) | | | | | | |
| Turn-On Delay Time | $V_{GS} = 10\text{V}, V_{DS} = 30\text{V},$ $I_D = 6\text{A}, R_G = 2\Omega$ | $t_{d(on)}$ | -- | 3 | -- | ns |
| Turn-On Rise Time | | t_r | -- | 20 | -- | |
| Turn-Off Delay Time | | $t_{d(off)}$ | -- | 14 | -- | |
| Turn-Off Fall Time | | t_f | -- | 19 | -- | |
| Source-Drain Diode | | | | | | |
| Forward Voltage (Note 3) | $V_{GS} = 0\text{V}, I_S = 6\text{A}$ | V_{SD} | -- | -- | 1.2 | V |
| Reverse Recovery Time | $I_S = 6\text{A},$ $di/dt = 100\text{A}/\mu\text{s}$ | t_{rr} | -- | 17 | -- | ns |
| Reverse Recovery Charge | | Q_{rr} | -- | 12 | -- | nC |

Notes:

1. Silicon limited current only.
2. $L = 0.3\text{mH}, V_{GS} = 10\text{V}, V_{DD} = 30\text{V}, R_G = 25\Omega, I_{AS} = 13\text{A}$, Starting $T_J = 25^\circ\text{C}$
3. Pulse test: Pulse Width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.
4. Switching time is essentially independent of operating temperature.

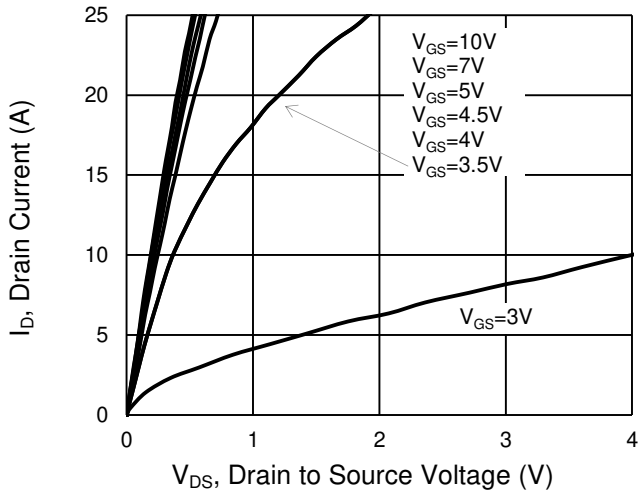
ORDERING INFORMATION

| ORDERING CODE | PACKAGE | PACKING |
|-------------------|---------|---------------------|
| TSM250NB06LCV RGG | PDFN33 | 5,000pcs / 13" Reel |

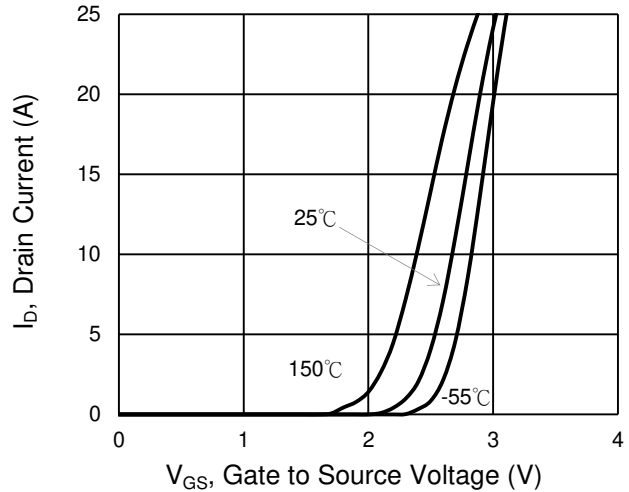
CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

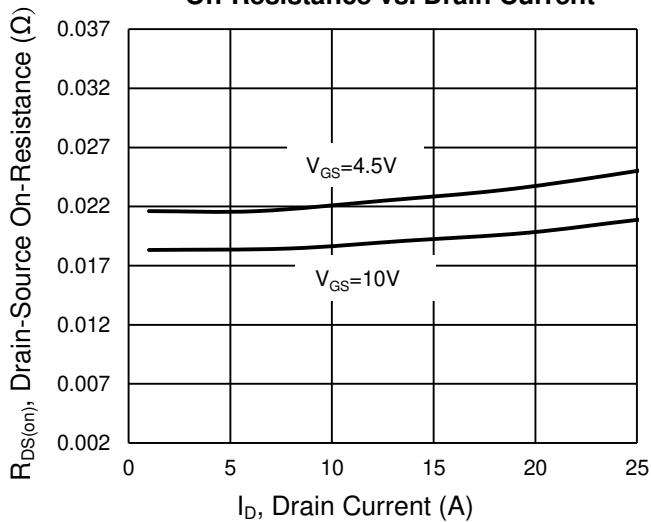
Output Characteristics



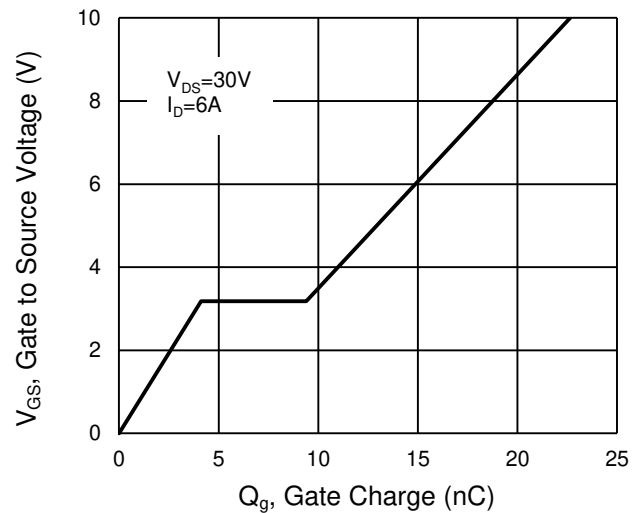
Transfer Characteristics



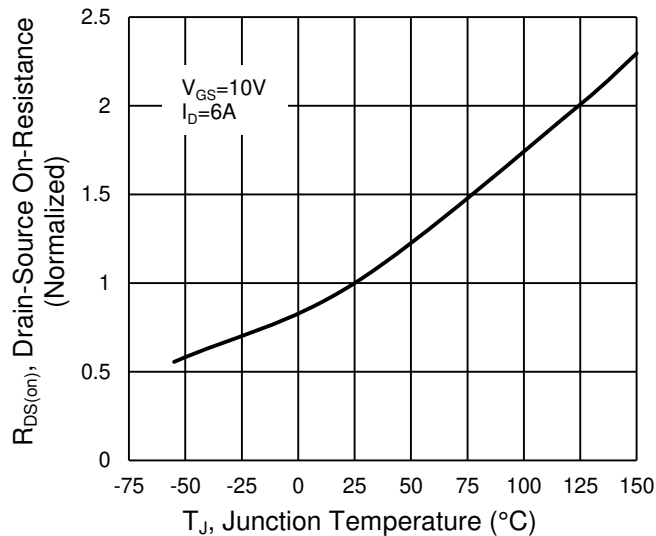
On-Resistance vs. Drain Current



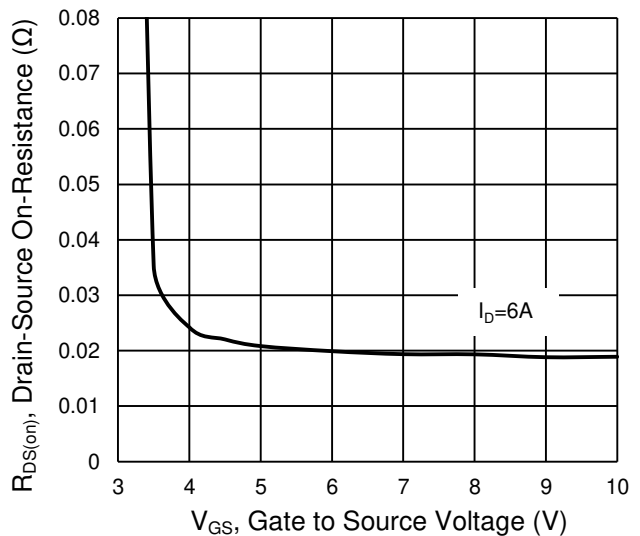
Gate-Source Voltage vs. Gate Charge



On-Resistance vs. Junction Temperature



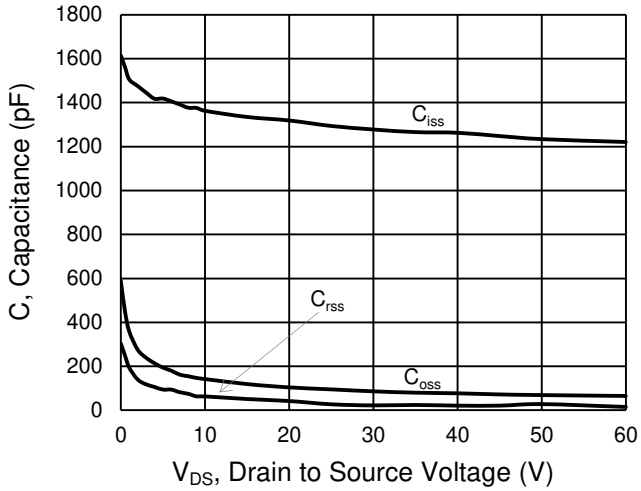
On-Resistance vs. Gate-Source Voltage



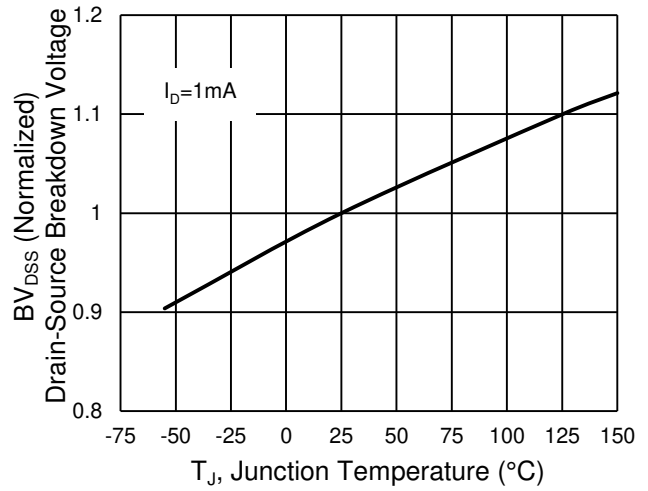
CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

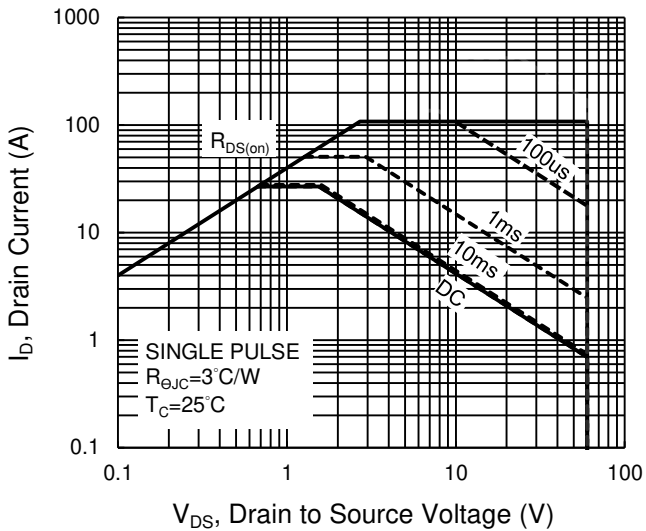
Capacitance vs. Drain-Source Voltage



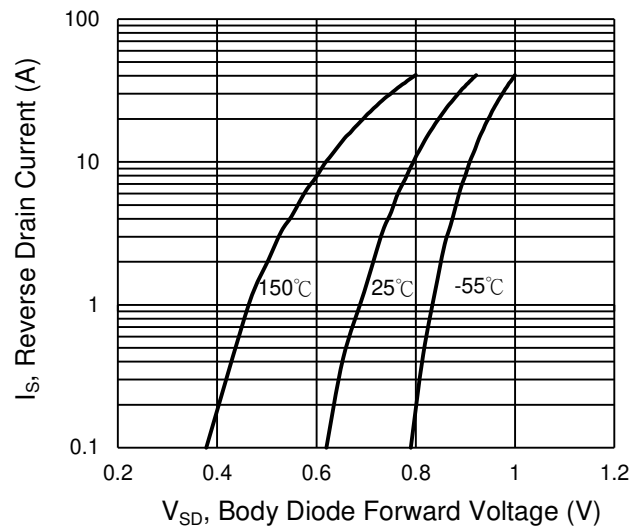
BV_{DSS} vs. Junction Temperature



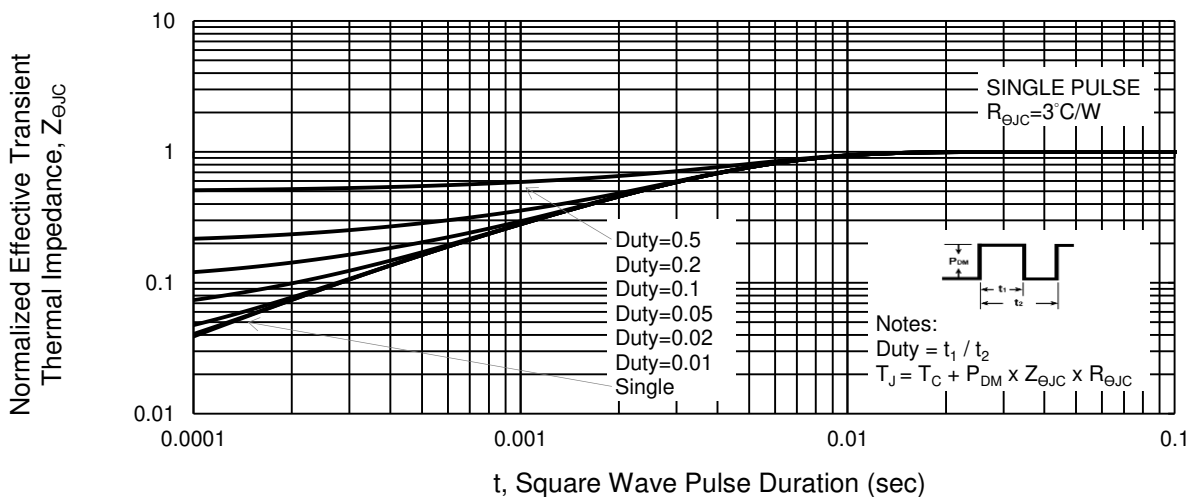
Maximum Safe Operating Area, Junction-to-Case



Source-Drain Diode Forward Current vs. Voltage

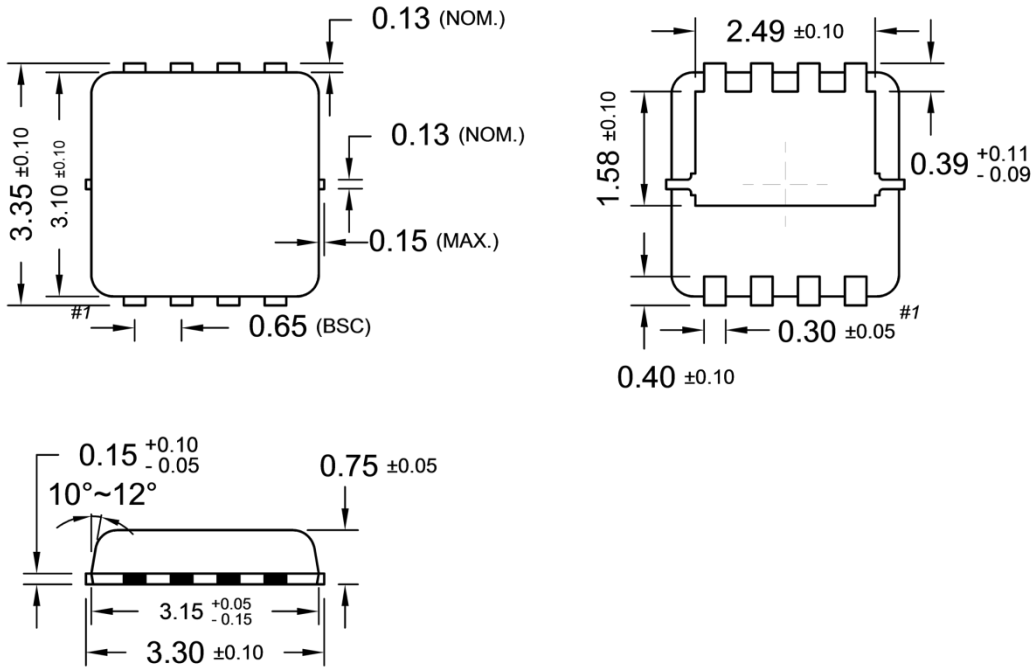


Normalized Thermal Transient Impedance, Junction-to-Case

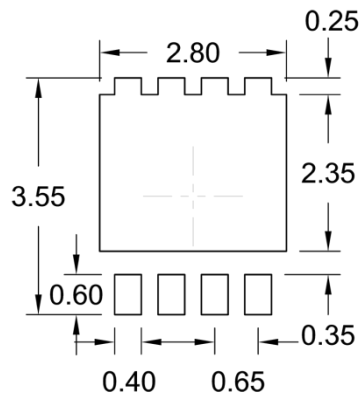


PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

PDFN33



SUGGESTED PAD LAYOUT (Unit: Millimeters)



MARKING DIAGRAM



- Y** = Year Code
- WW** = Week Code (01~52)
- L** = Lot Code (1~9,A~Z)
- F** = Factory Code

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